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FXL2T245 Low-Voltage, Dual-Supply, 2-Bit, Signal Translator with Configurable Voltage Supplies and Signal Levels and 3-State Outputs

Features

- Bi-Directional Interface between any 2 Levels from 1.1 V to 3.6 V
- Fully Configurable, Inputs Track V_{CC} Level
- Non-Preferential Power-up Sequencing; either V_{CC} maybe Powered-up First
- Outputs Remain in 3-State until Active V_{CC} Level is Reached
- Outputs Switch to 3-State if either V_{CC} is at GND
- Power-Off Protection
- Control Inputs (T/R, OE) Levels are Referenced to V_{CCA} Voltage
- Packaged in 10-Lead MicroPak (1.6 mm x 2.1 mm) Package
- ESD Protection Exceeds:
 - 4 kV HBM ESD JESD22-A114 & Mil Std 883e 3015.7)
 - 8kV HBM I/O to GND ESD (per JESD22-A114 & Mil Std 883e 3015.7)
 - 1 kV CDM ESD (per ESD STM 5.3)
 - 200 V MM ESD (per JESD22-A115 & ESD STM5.2)

Description

The FXL2T245 is a configurable, dual-voltage-supply translator designed for uni-directional and bi-directional voltage translation between two logic levels. The device allows translation between voltages as high as 3.6 V to as low as 1.1 V. The A port tracks the V_{CCA} level and the B port tracks the V_{CCB} level. This allows for bi-directional voltage translation over a variety of voltage levels: 1.2 V, 1.5 V, 1.8 V, 2.5 V, and 3.3 V.

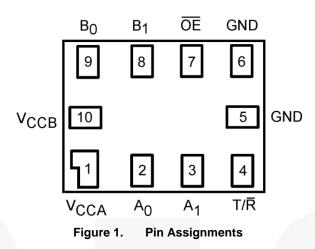
The device remains in 3-state until both $V_{CC}s$ reach active levels, allowing either V_{CC} to be powered-up first. Internal power-down control circuits place the device in 3-state if either V_{CC} is removed.

The Transmit / Receive (T/\overline{R}) input determines the direction of data flow through the device. The \overline{OE} input, when HIGH, disables both the A and B ports by placing them in a 3-state condition. The FXL2T245 is designed so control pins T/\overline{R} and \overline{OE} are supplied by V_{CCA} .

Ordering Information

Part Number	Operating Temperature Range	Package	Packing Method
FXL2T245L10X	-40°C to +85°C	10-Lead, MicroPak™, JEDEC MO255,1.6 x 2.1 mm	Tape and Reel

Pin Configuration



Pin Descriptions

Pin#	Pin Name	Description	
1	V _{CCA}	Side A Power Supply	
2	A ₀	Side A Inputs or 3-State Outputs	
3	A ₁	Side A Inputs or 3-State Outputs	
4	T/R	Transmit/Receive Input	
5, 6	GND	Ground	
7	0/E	Output Enable Input	
8 B ₁ Side B Inputs or 3- State Outputs		Side B Inputs or 3- State Outputs	
9	9 B ₀ Side B Inputs or 3-State Outputs		
10	V _{CCB}	CB Side B Power Supply	

Truth Table

Inj	outs	Outputs
ŌĒ	T/R	
LOW	LOW	Bus B Data to Bus A
LOW	HIGH	Bus A Data to Bus B

Notes:

1. LOW = low voltage level.

2. HIGH = high voltage level.

Functional Description

Power-Up / Power-Down Sequencing

Due to the chip design, the FXL2T245 translator offers the advantage of either V_{CC} being powered up first. When either V_{CC} is at 0 V, outputs are in a high-impedance state. The control inputs (T/R and \overline{OE}) are designed to track the V_{CCA} supply. A pull-up resistor tying \overline{OE} to V_{CCA} should be used to ensure that bus contention, excessive currents, or oscillations do not occur during power-up/power-down. The size of the pull-up resistor is based upon the current-sinking capability of the \overline{OE} driver.

The recommended power-up sequence is:

- 1. Apply power to either V_{CC}.
- Apply power to the T/R input (logic HIGH for A-to-B operation; logic LOW for B-to-A operation) and to the respective data inputs (A port or B port). This may occur at the same time as step 1.
- 3. Apply power to the other V_{CC} .
- 4. Drive the OE input LOW to enable the device.

The recommended power-down sequence is:

- 1. Drive \overline{OE} input HIGH to disable the device.
- 2. Remove power from either V_{CC} .
- 3. Remove power from the other V_{CC} .

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Conditions		Min.	Max.	Unit
V _{CCA}	Supply Voltage			-0.5	4.6	v
V _{CCB}	Supply Voltage			-0.5	4.6	V
		I/O Port A		-0.5	4.6	
VI	DC Input Voltage	I/O Port B		-0.5	4.6	V
		Control Inputs (T/R, OE)		-0.5	4.6	
		Output 3-State		-0.5	4.6	
Vo	Output Voltage ⁽³⁾	Output Active (An)	-0.5 to V_{CCA}	0.5	V	
		Output Active (B _n)	-0.5 to V_{CCB}	0.5		
I _{IK}	DC Input Diode Current	V ₁ < 0 V		-50	mA	
	DC Output Diode Current	V ₀ < 0 V		-50	mA	
I _{OK}		V _O > V _{CC}		+50	mA	
I _{OH} /I _{OL}	DC Output Source/Sink Cu	rrent			±50	mA
I _{CC}	DC V _{CC} or Ground Current	per Supply Pin			±100	mA
T _{STG}	Storage Temperature Rang	je		-65	+150	°C
		Human Body Model,	All Pins		4	
ESD	Electrostatic Discharge	JESD22-A114, Mil Std 883e 3015.7	I/O to GND		8	kV
ESD	Capability	Charged Device Model, JESD22-C10		1		
		Machine Model, JESD22-A115,STM	5.2		200	V

Note:

3. I/O absolute maximum ratings must be observed.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter		Conditions		Max.	Unit
Vcc	Power Supply	Operatir	ng V _{CCA} or V _{CCB}	1.1	3.6	V
		Port A		0	3.6	
VI	Input Voltage	Port B		0	3.6	V
		Control	Inputs (T/R, OE)	0	V _{CCA}	
			3.0 V to 3.6 V		±24	
			2.3 V to 2.7 V		±18	
I _{OH} /I _{OL}	Output Current	V _{cc}	V _{CC} 1.65 V to 1.95 V		±6	mA
			1.40 V to 1.65 V		±2	
			1.1 V to 1.4 V		±0.5	
T _A	Operating Temperature, Free Air	•		-40	+85	°C
$\Delta V / \Delta t$	Minimum Input Edge Rate	V _{CCA/B} =	1.1 V to 3.6 V		10	ns/V

Note:

4. All unused inputs must be held at V_{CCI} or GND.

Symbol	Parameter	Conditions	V _{cco} (V)	V _{CCI} (V)	Min.	Max.	Unit	
				2.70 to 3.60	2.00			
				2.30 to 2.70	1.60			
		Data Inputs An, Bn		1.65 to 2.30	0.65 x V _{CCI}			
				1.40 to 1.65	0.65 x V _{CCI}		1	
	HIGH Level		1 10 to 2 00	1.10 to 1.40	0.90 x V _{CCI}			
VIH	Input ⁽⁵⁾		1.10 to 3.60	2.70 to 3.60	2.00		V	
				2.30 to 2.70	1.60			
		Control Pins \overline{OE} , $\overline{T/R}$ (Referenced to V _{CCA})		1.65 to 2.30	$0.65 \times V_{CCA}$			
				1.40 to 1.65	$0.65 \times V_{CCA}$			
				1.10 to 1.40	$0.90 \times V_{CCA}$			
	10			2.70 to 3.60		0.80		
				2.30 to 2.70		0.70		
		Data Inputs An, Bn		1.65 to 2.30		0.35 x V _{CCI}		
				1.40 to 1.65		0.35 x V _{CCI}		
	LOW Level	6	1 10 to 2 00	1.10 to 1.40		0.10 x V _{CCI}		
VIL	Input ⁽⁵⁾		1.10 to 3.60	2.70 to 3.60		0.80	v	
				2.30 to 2.70		0.70		
		Control Pins \overline{OE} , $\overline{T/R}$ (Referenced to V _{CCA})		1.65 to 2.30		0.35 x V _{CCI}		
				1.40 to 1.65		0.35 x V _{CCI}		
				1.10 to 1.40		0.10 x V _{CCI}		
		I _{OH} = -100 µА	1.10 to 3.60	1.10 to 3.60	V _{CC0} - 0.20			
		I _{OH} = -12 mA	2.70	2.70	2.20			
		I _{ОН} = -18 mA	3.00	3.00	2.40			
		I _{OH} = -24 mA	3.00	3.00	2.20			
Mari	HIGH Level	I _{ОН} = -6 mA	2.30	2.30	2.00		v	
Vон	Output ⁽⁶⁾	I _{OH} = -12 mA	2.30	2.30	1.80		v	
		I _{ОН} = -18 mA	2.30	2.30	1.70			
		I _{OH} = -6 mA	1.65	1.65	1.25			
		I _{ОН} = -2 mA	1.40	1.40	1.05			
		I _{OH} = -0.5 mА	1.10	1.10	$0.75 \ x \ V_{CC0}$			
		I _{OL} = 100 μA	1.10 to 3.60	1.10 to 3.60		0.20		
		I _{OL} = 12 mA	2.70	2.70		0.40		
		I _{OL} = 18 mA	3.00	3.00		0.40		
		I _{OL} = 24 mA	3.00	3.00		0.55		
V_{OL}	LOW Level Output ⁽⁶⁾	I _{OL} = 12 mA	2.30	2.30		0.40	V	
		I _{OL} = 18 mA	2.30	2.30		0.60		
		I _{OL} = 6 mA	1.65	1.65		0.30		
		$I_{OL} = 2 \text{ mA}$	1.40	1.40		0.35		
		$I_{OL} = 0.5 \text{ mA}$	1.10	1.10		0.30 x V _{CC0}		

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Symbol	Parameter	Conditions	V _{cco} (V)	V _{cci} (V)	Min.	Max.	Unit
ار	Input Leakage Current, Control Pins	V _I =V _{CCA} or GND	3.60	1.10 to 3.60		±1.0	μA
	Power Off	A_n , V ₁ or V ₀ =0 V to 3.6 V	3.60	0		±10	μA
I _{OFF} Leakage Current		B_n , V ₁ or V ₀ =0 V to 3.6 V	0	3.60		±10	
	3-State Output	A _n , B _n , /OE=V _{IH}	3.60	3.60		±10	μA
loz	Leakage $(0 \le V_0 \le 3.6 V,$	B _n , /OE= Don't Care ⁽⁷⁾	3.60	0		±10	
	V _I =V _{IH} or V _{IL})	A _n , /OE= Don't Care ⁽⁷⁾	0	3.60		±10	
I _{CCA/B}			1.10 to 3.60	1.10 to 3.60	1	20	μA
I _{CCZ}		V _I =V _{CCI} or GND; I _O =0	1.10 to 3.60	1.10 to 3.60		20	
	Quiescent		1.10 to 3.60	0		-10	
ICCA	Supply Current ⁽⁸⁾	V _I =V _{CCA} or GND; I ₀ =0	0	1.10 to 3.60		10	
			0	1.10 to 3.60		-10	
ССВ		V _I =V _{CCB} or GND; I _O =0	1.10 to 3.60	0		10	
∆I _{CCA/B}	Increase in I _{CC} per Input; Other Inputs at V _{CC} or GND	V _{IH} =3.0 V	3.60	3.60		500	μA

Notes:

5. V_{CCI} = the V_{CC} associated with the data input under test.

6. V_{CCO} = the V_{CC} associated with the output under test.

7. Don't care = any valid logic level.

8. Reflects current per supply, V_{CCA} or V_{CCB}.

						T _A = -40	to +85°0)				
Symbol	Parameter		=3.0 V 8.6 V		=2.3 V 2.7 V		1.65 V .95 V		=1.4 V I.6 V		=1.1 V 1.3V	Unit
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
V _{CCA} =3.0	V to 3.6 V											
t _{PLH,} t _{PHL}	Propagation Delay A to B	0.2	3.5	0.3	3.9	0.5	5.4	0.6	6.8	1.4	22.0	ns
IPLH, IPHL	Propagation Delay B to A	0.2	3.5	0.2	3.8	0.3	4.0	0.5	4.3	0.8	13.0	
t t	Output Enable /OE to B	0.5	4.0	0.7	4.4	1.0	5.9	1.0	6.4	1.5	17.0	- ns
t _{PZH,} t _{PZL}	Output Enable /OE to A	0.5	4.0	0.5	4.0	0.5	4.0	0.5	4.0	0.5	4.0	115
	Output Disable /OE to B	0.2	3.8	0.2	4.0	0.7	4.8	1.5	6.2	2.0	17.0	
t _{PHZ,} t _{PLZ}	Output Disable /OE to A	0.2	3.7	0.2	3.7	0.2	3.7	0.2	3.7	0.2	3.7	- ns
V _{CCA} =2.3	V to 2.7 V											
	Propagation Delay A to B	0.2	3.8	0.4	4.2	0.5	5.6	0.8	6.9	1.4	22.0	ns
t _{PLH,} t _{PHL}	Propagation Delay B to A	0.3	3.9	0.4	4.2	0.5	4.5	0.5	4.8	1.0	7.0	
	Output Enable /OE to B	0.6	4.2	0.8	4.6	1.0	6.0	1.0	6.8	1.5	17.0	
t _{PZH} , t _{PZL}	Output Enable /OE to A	0.6	4.5	0.6	4.5	0.6	4.5	0.6	4.5	0.6	4.5	- ns
	Output Disable /OE to B	0.2	4.1	0.2	4.3	0.7	4.8	1.5	6.7	2.0	17.0	
t _{PHZ,} t _{PLZ}	Output Disable /OE to A	0.2	4.0	0.2	4.0	0.2	4.0	0.2	4.0	0.2	4.0	- ns
V _{CCA} =1.6	5 V to 1.95 V											
	Propagation Delay A to B	0.3	4.0	0.5	4.5	0.8	5.7	0.9	7.1	1.5	22.0	
t _{PLH} , t _{PHL}	Propagation Delay B to A	0.5	5.4	0.5	5.6	0.8	5.7	1.0	6.0	1.2	8.0	– ns
. .	Output Enable /OE to B	0.6	5.2	0.8	5.4	1.2	6.9	1.2	7.2	1.5	18.0	
t _{PZH,} t _{PZL}	Output Enable /OE to A	1.0	6.7	1.0	6.7	1.0	6.7	1.0	6.7	1.0	6.7	ns
4 ·	Output Disable /OE to B	0.2	5.1	0.2	5.2	0.8	5.2	1.5	7.0	2.0	17.0	
t _{PHZ,} t _{PLZ}	Output Disable /OE to A	0.5	5.0	0.5	5.0	0.5	5.0	0.5	5.0	0.5	5.0	ns

FXL2T245 — Low Voltage Dual Supply 2-Bit Signal Translator with Configurable Voltage Supplies

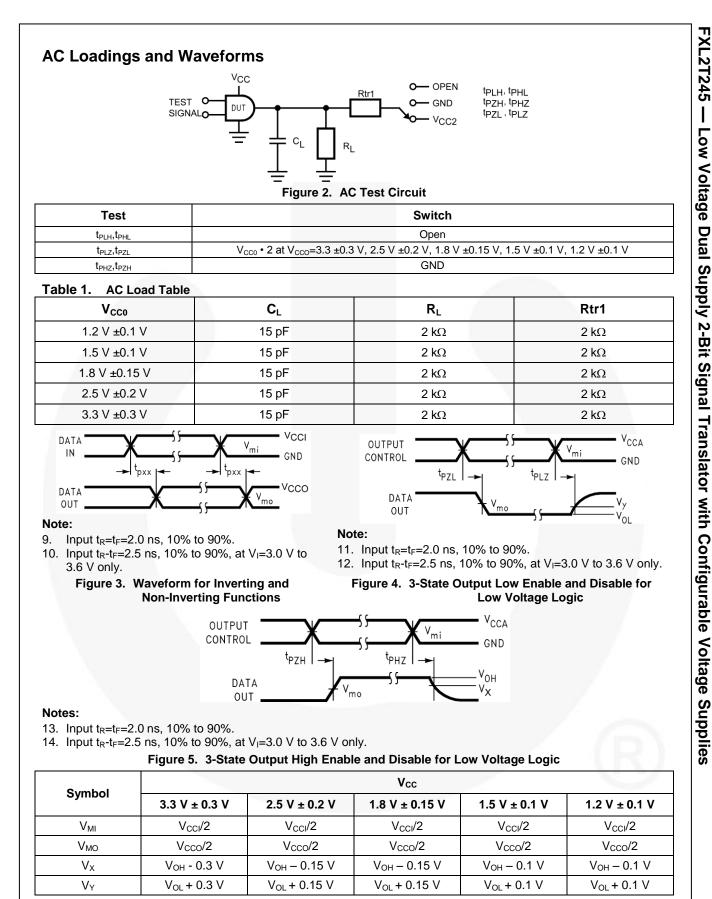
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	ctrical Chara	Icteris	STICS			T40	to +85°C	<u> </u>				
Symbol	Parameter	V _{CCB} =3.0 V to 3.6 V			=2.3 V 2.7 V	V _{CCB} =	1.65 V .95 V	V _{CCB} =1.4 V to 1.6 V		V _{CCB} =1.1 V to 1.3V		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
V _{CCA} =1.4	V to 1.6 V			1								
+ +	Propagation Delay A to B	0.5	4.3	0.5	4.8	1.0	6.0	1.0	7.3	1.5	22.0	-
t _{PLH,} t _{PHL}	Propagation Delay B to A	0.6	6.8	0.8	6.9	0.9	7.1	1.0	7.3	1.3	9.5	- ns
+ +	Output Enable /OE to B	1.1	7.5	1.1	7.6	1.3	7.7	1.4	7.9	2.0	20.0	20
t _{PZH,} t _{PZL}	Output Enable /OE to A	1.0	7.5	1.0	7.5	1.0	7.5	1.0	7.5	1.0	7.5	- ns
	Output Disable /OE to B	0.4	6.1	0.4	6.2	0.9	6.2	1.5	7.5	2.0	18.0	
t _{PHZ} , t _{PLZ}	Output Disable /OE to A	1.0	6.0	1.0	6.0	1.0	6.0	1.0	6.0	1.0	6.0	- ns
V _{CCA} =1.1	V to 1.3 V											
	Propagation Delay A to B	0.8	13.0	1.0	7.0	1.2	8.0	1.3	9.5	2.0	24.0	
t _{PLH,} t _{PHL}	Propagation Delay B to A	1.4	22.0	1.4	22.0	1.5	22.0	1.5	22.0	2.0	24.0	ns
	Output Enable /OE to B	1.0	12.0	1.0	9.0	2.0	10.0	2.0	11.0	2.0	24.0	
t _{PZH} , t _{PZL}	Output Enable /OE to A	2.0	22.0	2.0	22.0	2.0	22.0	2.0	22.0	2.0	22.0	0 ns
	Output Disable /OE to B	1.0	15.0	0.7	7.0	1.0	8.0	2.0	10.0	2.0	20.0	
t _{PHZ,} t _{PLZ}	Output Disable /OE to A	2.0	15.0	2.0	12.0	2.0	12.0	2.0	12.0	2.0	12.0	ns

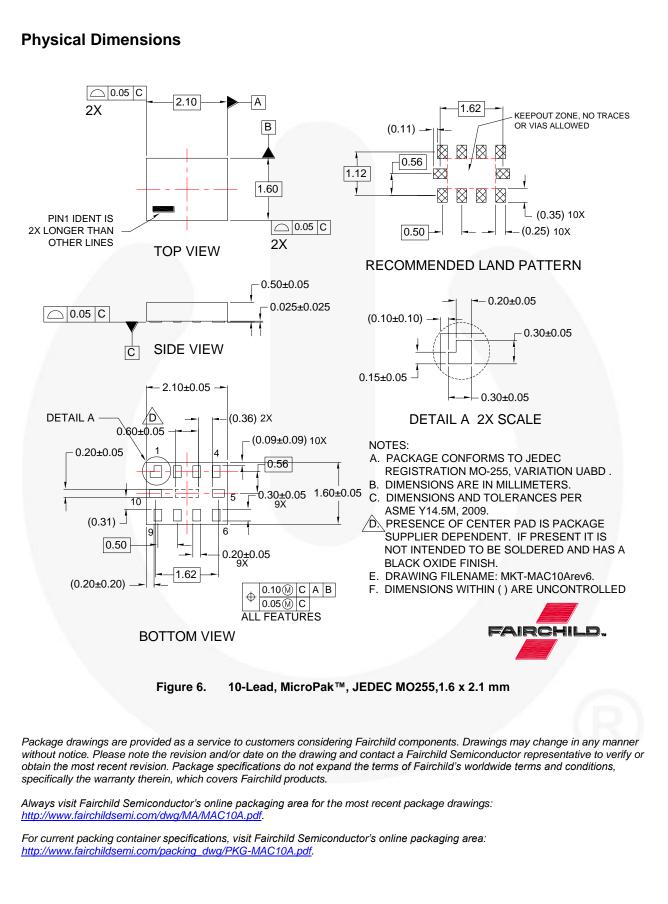
Capacitance

Symbol	Parameter	Conditions	T _A =+25°C	Unit
Symbol	Farameter	Conditions	Typical	Unit
C _{IN}	Input Capacitance (Pins O/E, TR)	$V_{CCA}=V_{CCB}=3.3 \text{ V}, V_I=0 \text{V or } V_{CCA/B}$	4	pF
C _{I/O}	Input / Output Capacitance An, Bn Ports	$V_{CCA} = V_{CCB} = 3.3$ V, $V_I = 0V$ or $V_{CCA/B}$	5	pF
C _{PD}	Power Dissipation Capacitance	$V_{\text{CCA}}{=}V_{\text{CCB}}{=}3.3$ V, $V_{\text{I}}{=}0V$ or $V_{\text{CC}},$ f=10 MHz	20	pF



Note:

15. For $V_{MI} V_{CCO} = V_{CCA}$ for control pins T/\overline{R} and \overline{OE} or $V_{CCA}/2$.





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Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Surces. Fairchild to combat this global problem and encourage our customers to do their part in stopping this practice by bying direct or from authorized distributors.

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Definition of Terms		
Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

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